

QT625C XO DETAIL SPECIFICATION

Specification Control Drawing

Scope

Scope Part Number

Applicable Documents

Specifications and Standards

Requirements

General Requirements Approved Manufacturer Design and Construction **Outline Dimensions and Terminal Connections** Package Body and Lead Finish Active Devices Use of National Semiconductor Corporation (NSC) Radiation Hard CMOS Performance Requirements Maximum Ratings Electrical Performance Characteristics and Limits **Delta** Limits sheet.Directory Total Dose Radiation Limits

Quality Assurance Provisions

General Screening Tests Quality Conformance Inspection

Packaging

Preservation, Packaging and Packing

Notes

Ordering Information Part Number Table I. Stability/Temperature Options

Source of Supply

Approved Manufacturer

Table II. Maximum Ratings

Table III. Electrical Performance Characteristics

Figure. 1. Package Dimensions and Terminal Connections

			к	EVISIONS				
REVISION		D	ESCRIPTIC	ON		DATE		APPROVE
-	Initial release							
А	Include parag	raph 3.3.3.1 clarification o	f microcircuit te	echnology, SEL rat	ing	7/17/07	,	
В	Clarification,	2/14/08	;					
С	Change to mi	8/04/08	;					
D	Clarification,	paragraph 3.3.3.1. Add HC	CMOS logic opt	tion.		8/27/08	;	E.Jackson
		CUMENT IS COI COPY OR DISTF						
SPECIF	FICATION	I CONTROL DRA	AWING					
SPECIF	FICATION	I CONTROL DRA	AWING DATE	Q-TECH C 10150 W.		DN I BLVD.		
UNLESS OTH	HERWISE NSIONS ARE		_	Q-TECH C 10150 W. CULVER (JEFFERSON CITY, CA. 90	DN I BLVD. 0232-3510		
UNLESS OTH SPECIFIED DIMEI IN INCH	HERWISE NSIONS ARE IES.	PREPARED BY	DATE	Q-TECH C 10150 W. CULVER C	JEFFERSON CITY, CA. 90 CRYSTAL C	DN I BLVD. 0232-3510 0SCILLATO	9R +5	V, CLASS
UNLESS OTH	HERWISE NSIONS ARE IES. ICES: MAL = .005	PREPARED BY E.Jackson CHECKED BY	DATE 8/27/08 DATE	Q-TECH C 10150 W. CULVER C	JEFFERSON CITY, CA. 90 CRYSTAL C	DN I BLVD. 0232-3510	9R +5	V, CLASS
UNLESS OTH SPECIFIED DIMEI IN INCH TOLERAN 3 PLACE DECI	HERWISE NSIONS ARE IES. ICES: MAL = .005 IMAL = .02	PREPARED BY E.Jackson	DATE 8/27/08	Q-TECH C 10150 W. CULVER C	JEFFERSON CITY, CA. 90 CRYSTAL C	DN I BLVD. 0232-3510 0SCILLATO	9R +5	V, CLASS
UNLESS OTH SPECIFIED DIMEI IN INCH 3 PLACE DECI 2 PLACE DECI 1 PLACE DEC FRACTIONS	HERWISE NSIONS ARE IES. ICES: IMAL = .005 IMAL = .02 CIMAL = .1 = ± 1/16	PREPARED BY E.Jackson CHECKED BY	DATE 8/27/08 DATE	Q-TECH C 10150 W. CULVER C HYBRID C	JEFFERSON CITY, CA. 90 CRYSTAL C DETAIL SP	DN I BLVD. 0232-3510 0SCILLATO	9R +5	V, CLASS OR
UNLESS OTH SPECIFIED DIMEI IN INCH TOLERAN 3 PLACE DECI 2 PLACE DECI 1 PLACE DECI 1 PLACE DECI	HERWISE NSIONS ARE IES. ICES: IMAL = .005 IMAL = .02 CIMAL = .1 = ± 1/16	PREPARED BY E.Jackson CHECKED BY T.Villegas	DATE 8/27/08 DATE 10/9/08	Q-TECH C 10150 W. CULVER C HYBRID C DRAWING NO.	JEFFERSON CITY, CA. 90 CRYSTAL C DETAIL SP QT6	ON I BLVD. 0232-3510 OSCILLATO ECIFICATIO	9R +5	V, CLASS OR
UNLESS OTH SPECIFIED DIMEI IN INCH 3 PLACE DECI 2 PLACE DECI 1 PLACE DEC FRACTIONS	HERWISE NSIONS ARE IES. ICES: IMAL = .005 IMAL = .02 CIMAL = .1 = ± 1/16	PREPARED BY E.Jackson CHECKED BY T.Villegas	DATE 8/27/08 DATE 10/9/08	Q-TECH C 10150 W. CULVER C HYBRID C	JEFFERSON CITY, CA. 90 CRYSTAL C DETAIL SP	ON I BLVD. 0232-3510 OSCILLATO ECIFICATIO	9R +5' ON FO	V, CLASS OR

1 SCOPE

- 1.1 <u>Scope.</u> This specification establishes the detail requirements for hybrid, hermetically sealed, crystal oscillators for use in space flight missions.
- 1.2 <u>Part number.</u> The part number shall be as specified in Table I herein.

2 APPLICABLE DOCUMENTS

2.1 <u>Specifications and standards.</u> Unless otherwise specified, the following documents shall be applicable to this specification to the extent specified herein.

SPECIFICATIONS

401-0298-001 Hybrid Crystal C

Hybrid Crystal Oscillators, Class S, General Specification For

3 REQUIREMENTS

- 3.1 <u>General requirements.</u> The individual item requirements shall be as specified in the General Specification with the exceptions, modifications, and additions specified herein.
- 3.2 <u>Approved manufacturer.</u> Hybrid crystal oscillators shall be supplied from the manufacturer specified in paragraph 7.1 herein.
- 3.3 Design and construction.
- 3.3.1. <u>Outline dimensions and terminal connections.</u> The outline dimensions and terminal connections shall be as shown in Figure 1 herein.
- 3.3.2. <u>Package body and lead finish.</u> The package body and lead finish shall be gold in accordance with MIL-PRF-38534.
- 3.3.3. <u>Active Devices.</u> The microcircuit used in this part shall use CMOS technology and shall be from a wafer proven to be radiation tolerant to 100 kRad (Si) total ionizing dose.
- 3.3.3.1 <u>CMOS microcircuit usage.</u> For frequencies below 12 MHZ the output microcircuit shall be Intersil Corporation 54ACS/HCS family, Silicon on Sapphire CMOS technology. For frequencies greater than or equal to 12 MHZ, the CMOS microcircuit shall be 54AC00, see DSSC SMD 5962-87549. This microcircuit is specified to be *single event latchup free* for LET up to 93 MeV-cm²/mg. For output frequencies from 12 MHZ to 100 MHZ, the manufacturer shall be ST Microelectronics Corporation; for output frequencies greater than 100 MHZ, the manufacturer shall be National Semiconductor Corporation
- 3.4 <u>Performance requirements.</u>
- 3.4.1. <u>Maximum ratings.</u> The maximum ratings shall be as specified in Table II herein.
- 3.4.2. <u>Electrical performance characteristics and limits.</u> The electrical performance requirements and limits shall be in accordance with Table III herein.
- 3.4.3. <u>Delta limits.</u> Except for frequency aging (refer to Table III), delta limits shall be in accordance with the General Specification.
- 3.4.4. <u>Total dose radiation limits.</u> Hybrid crystal oscillators supplied in accordance with this specification shall be capable of meeting the performance requirements after being exposed to 100 krad total dose radiation levels.

4 QUALITY ASSURANCE PROVISIONS

- 4.5 <u>General.</u> The quality assurance provisions shall be in accordance with the General Specification with the exceptions, modifications, and additions specified herein.
- 4.6 <u>Screening tests.</u> The screening tests shall be in accordance with the General Specification.
 4.7 <u>Quality Conformance Inspection.</u> Quality Conformance Inspection shall be in accordance with the General Specification and shall be required only when specified by the purchase order.

5 PACKAGING

5.1 <u>Preservation, packaging and packing.</u> Hybrid crystal oscillators shall be prepared for delivery in accordance with the General specification.

6 NOTES

- 6.1 <u>Notes.</u> The notes of the General Specification are applicable to this drawing.
- 6.2 <u>Ordering information.</u> The procuring activity shall advise Q-Tech Corporation at the time of Request for Quotation if quality conformance inspection is to be required.
- 6.3 Part number.

<u>QT625</u> <u>C</u> <u>B</u> <u>1</u> <u>M</u> - <u>16.000000 MHZ</u>

Model #
Supply voltage: C: + 5.0 volts
Temp stability - see Table I
Duty cycle: 1: 60/40%
2: 45/55% (available up to 100MHz)
Screening: E: engineering model; M: flight model

Frequency (8 digits)

TABLE I. STABILITY / TEMPERATURE OPTIONS					
OPTION	TEMP STABILITY				
Α	± 65 PPM, - 55 °C TO + 125 °C				
В	± 50 PPM, - 55 °C TO + 125 °C				
С	± 50 PPM, - 55 °C TO + 105 °C				
D	± 40 PPM, - 55 °C TO + 105 °C				
E	± 30 PPM, - 40 °C TO + 85 °C				
F	± 50 PPM, - 20 °C TO + 70 °C				
G	± 25 PPM, - 20 °C TO + 70 °C				
H *	± 5 PPM, 0 °C TO + 55 °C				

* Frequency/Temperature stability (tolerance) shall be referenced to the specified nominal output frequency, except for temp code H, in which case it is with reference to room temperature (T = 25 ± 2 °C). For temp code H, room temperature tolerance shall be ± 10 PPM.

7 SOURCE OF SUPPLY

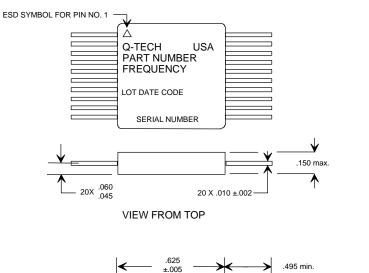
7.1 <u>Approved manufacturer.</u>

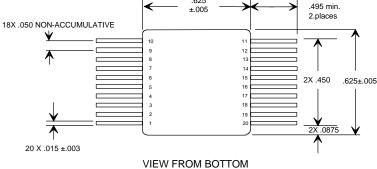
Q-Tech Corporation 10150 W. Jefferson Blvd. Culver City, Ca. 90232 U.S.A.

	Parameter		Symbol	Min		Max	Un	its	
S	Supply voltage		V _{cc}	0		7	Vc	olts	
0	perating temperature		Tc	-55		125		С	
	torage temperature		Tstg	-65		150		С	
	ead solder temperature/time					250/10		conds	
Pa	ackage thermal resistance		θјс			50	°C	/W	
	TABLE III. ELE	CTRI			HARAG	TERIST	CS		
ELECT	LECTRICAL PARAMETER		FEST CONDITIONS 2/,3/		LIMITS				NOTES
					MIN.	NOM.	MAX.	UNITS	
FREQUENCY	RANGE				0.05		150	MHz	
FREQUENCY	TEMPERATURE STABILITY				See Table I			1/, 4/	
SUPPLY VOL	TAGE				4.5	5	5.5	Vdc	
	INPUT CURRENT		out frequency:				•		
Measured without load at 5.5 Vdc		Less than 12 MHZ					12	mA	
		12 MHZ - 59.99 MHZ					25	mA	
		60 MHZ - 99.99 MHZ					45	mA	
		100 MHZ - 150 MHZ				60	mA		
LOAD						CMOS		-	6/
OUTPUT VOL	TAGE - LOGIC "0"						V _{cc} x 0.1	Vdc	5/
OUTPUT VOLTAGE - LOGIC "1"					V _{cc} x 0.9			Vdc	
OUTPUT WAVEFORM					Squarewave N/A		N/A		
RISE / FALL TIME (worst case, @Vcc = 4.5, and T = 125 °C)		Outp	out frequency:						
		B	elow 12 MHZ				7	nS	6/
		12 MHZ - 80 MHZ					3.5	nS	6/
		>	80 MHZ				2.5	nS	6/
DUTY CYCLE		C	Option 1:		60/40 or better			%	
		Option 2: (<= 100 MHz)		45/55 or better			%		
FREQUENCY AGING (AFTER 30 DAYS)			70 °C ± 3°	C	±1.5 p		ppm		
FREQUENCY	AGING (AFTER 1 YEAR)		70 °C ± 3°	C			±10	ppm	
STARTUP TIME							10	ms	

<u>NOTES</u>

- 1. The limit for frequency/temperature stability (tolerance) shall be referenced to the specified nominal output frequency.
- 2. Unless otherwise specified the limits are over the full operating temperature range, under specified load conditions and at nominal supply voltage.
- 3. Unless otherwise specified, all measurements are in accordance with MIL-PRF-55310.
- 4. Up to 30 days after shipment.
- 5. Voltage values are with respect to network ground terminal.
- 6. A standard CMOS load of 10 kOhm || 15 pF shall be used. See MIL-PRF-55310/26 for CMOS waveform measurement definitions.





NOTES:

- 1. Dimensions are in inches.
- 2. Lead numbers are for reference only and are not marked on the unit.
- 3. All pins with function NC may not be connected as external tie or connections, except they may be tied to Ground.

TERMINAL CONNECTIONS								
TERMINAL NO.	CONNECTION	TERMINAL NO.	CONNECTION					
1	N/C	11	OUTPUT					
2	N/C	12	GND/CASE *					
3	N/C	13	V _{cc}					
4	N/C	14	N/C					
5	N/C	15	GND/CASE *					
6	N/C	16	N/C					
7	N/C	17	N/C					
8	N/C	18	N/C					
9	N/C	19	N/C					
10	GND/CASE	20	N/C					

* Additional optional Ground connections are included only when microcircuit used is 54AC00 (see paragraph 3.3.3.1), and may be connected to circuit ground plane for minimum overshoot/ringing when driving capacitive loads.

FIGURE 1. PACKAGE DIMENSIONS AND TERMINAL CONNECTIONS

Q-Tech Corporation 10150 W. Jefferson Blvd. Culver City, CA. 90232